









	<h2 style="color: red;">RFD3055LESM</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">RFD3055LESM</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 11A TO-252AA</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">RFD3055LESM.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 76223 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">RFD3055LESM</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 60V 11A TO-252AA
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	76223 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252AA
Verlustleistung (max)	38W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	11A (Tc)
Rds On (Max) @ Id, Vgs	107 mOhm @ 8A, 5V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	11.3nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	350pF @ 25V
Verpackung	Tube

RFD3055LESM ist neu im Original, Suche RFD3055LESM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RFD3055LESM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage RFD3055LESM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>RFD3055LESM9A</b> Fairchild/ON Semiconductor MOSFET N-CH 60V 11A TO-252AA</p>	 <p><b>RFD3055</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 12A IPAK</p>	 <p><b>RFD3055LESM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 11A TO-252AA</p>	 <p><b>RFD3055RLESM96</b> FAIRCHILD RFD3055RLESM96 FAIRCHILD</p>
 <p><b>RFD3055LE</b> Fairchild/ON Semiconductor MOSFET N-CH 60V 11A I-PAK</p>	 <p><b>RFD3055LESM9A</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 11A TO-252AA</p>	 <p><b>RFD3055LESM9AS2568</b> FAIRCHILD RFD3055LESM9AS2568 FAIRCHILD</p>	 <p><b>RFD3055RLESM9A</b> Original RFD3055RLESM9A Original</p>

### heiße Teile

Mehr

RFD16N03LSM9A	RFD16N05	RFD16N05	RFD16N05L	RFD16N05LSM
RFD16N05LSM	RFD16N05LSM-NL	RFD16N05LSM96S5000	RFD16N05LSM9A	RFD16N05LSM9A
RFD16N05SM	RFD16N05SM	RFD16N05SM9A	RFD16N05SM9A	RFD16N06
RFD16N06L	RFD16N06LESM	RFD16N06LESM9A	RFD16N06LESM9A	RFD16N06SM9A
RFD20N03SM	RFD20N03SM9A	RFD3055L	RFD3055LE	RFD3055LE
RFD3055LESM	RFD3055LESM9A	RFD3055LESM9A	RFD3055LESM9AS2568	RFD3055RLESM96
RFD3055RLESM9A	RFD3055SM	RFD3055SM	RFD3055SM9A	RFD3055SM9A
RFD4N06LSM	RFD8P05SM	RFD8P05SM	RFD8P05SM9A	RFD8P06ESM
RFD8P06ESM9A	RFD8P06LESM	RFD8P06LESM9A4407	RFD8P06SM	RFD8P06TM
RFDA2026	RFDA2026TR13	RFDIP1608060T1T	RFDIP1608060TM7T62	RFDIP1608060TM8T62

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